

## DATA SHEET

# NEC

### NPN SILICON RF TRANSISTOR

# NE687M33

### NPN SILICON RF TRANSISTOR FOR HIGH-FREQUENCY LOW NOISE 3-PIN SUPER LEAD-LESS MINIMOLD (M33)

#### FEATURES

- Low noise  
NF = 1.5 dB TYP. @  $V_{CE} = 1\text{ V}$ ,  $I_C = 3\text{ mA}$ ,  $f = 2\text{ GHz}$
- ★ • 3-pin super lead-less minimold (M33) package

#### ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE687M33	50 pcs (Non reel)	• 8 mm wide embossed taping
NE687M33-T3	10 kpcs/reel	• Pin 2 (Base) face the perforation side of the tape

**Remark** To order evaluation samples, contact your nearby sales office.  
The unit sample quantity is 50 pcs.

#### ABSOLUTE MAXIMUM RATINGS ( $T_A = +25^\circ\text{C}$ )

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	$V_{CBO}$	5.0	V
Collector to Emitter Voltage	$V_{CEO}$	3.0	V
Emitter to Base Voltage	$V_{EBO}$	2.0	V
Collector Current	$I_C$	30	mA
Total Power Dissipation	$P_{tot}$ <small>Note</small>	90	mW
Junction Temperature	$T_j$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-65 to +150	$^\circ\text{C}$

**Note** Mounted on  $1.08\text{ cm}^2 \times 1.0\text{ mm}$  (t) glass epoxy PCB

**Caution** Observe precautions when handling because these devices are sensitive to electrostatic discharge.

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Not all devices/types available in every country. Please check with local NEC Compound Semiconductor Devices representative for availability and additional information.

**ELECTRICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$ )**

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = 5\text{ V}, I_E = 0\text{ mA}$	—	—	100	nA
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = 1\text{ V}, I_C = 0\text{ mA}$	—	—	100	nA
DC Current Gain	$h_{FE}$ <sup>Note 1</sup>	$V_{CE} = 1\text{ V}, I_C = 10\text{ mA}$	70	110	140	—
RF Characteristics						
Gain Bandwidth Product	$f_T$	$V_{CE} = 1\text{ V}, I_C = 10\text{ mA}, f = 2\text{ GHz}$	10	12	—	GHz
Insertion Power Gain	$ S_{21e} ^2$	$V_{CE} = 1\text{ V}, I_C = 10\text{ mA}, f = 2\text{ GHz}$	7	9	—	dB
Noise Figure	NF	$V_{CE} = 1\text{ V}, I_C = 3\text{ mA}, f = 2\text{ GHz}, Z_S = Z_{opt}$	—	1.5	2.0	dB
Reverse Transfer Capacitance	$C_{re}$ <sup>Note 2</sup>	$V_{CB} = 0.5\text{ V}, I_C = 0\text{ mA}, f = 1\text{ MHz}$	—	0.4	0.7	pF

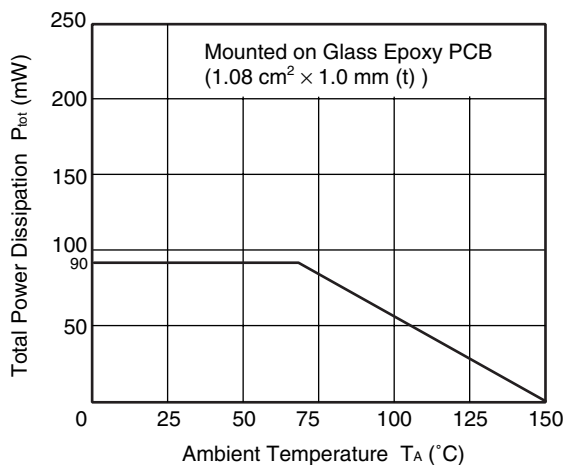
- Notes** 1. Pulse measurement:  $PW \leq 350\text{ }\mu\text{s}$ , Duty Cycle  $\leq 2\%$   
2. Collector to base capacitance when the emitter grounded

**$h_{FE}$  CLASSIFICATION**

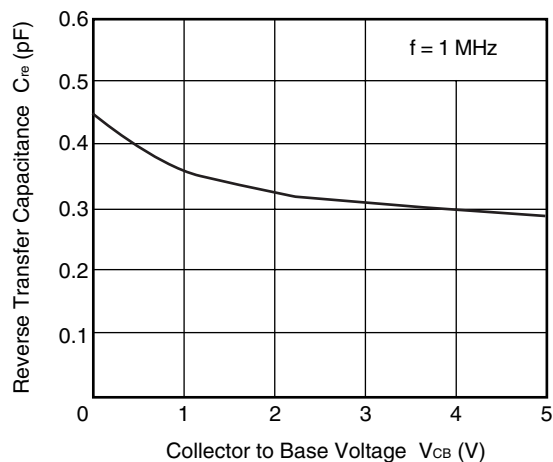
Rank	FB
Marking	W2
$h_{FE}$ Value	70 to 140

★ TYPICAL CHARACTERISTICS ( $T_A = +25^\circ\text{C}$  ,unless otherwise specified)

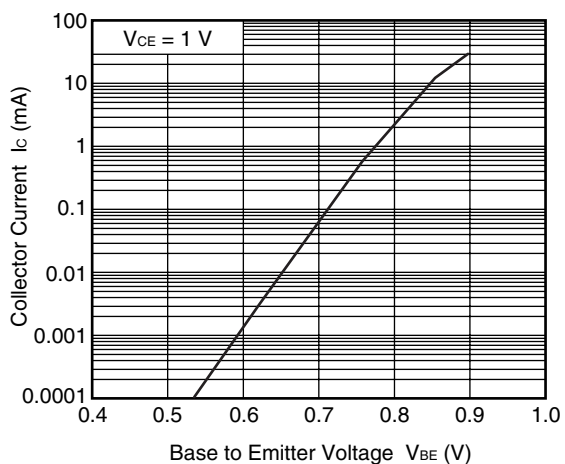
TOTAL POWER DISSIPATION  
vs. AMBIENT TEMPERATURE



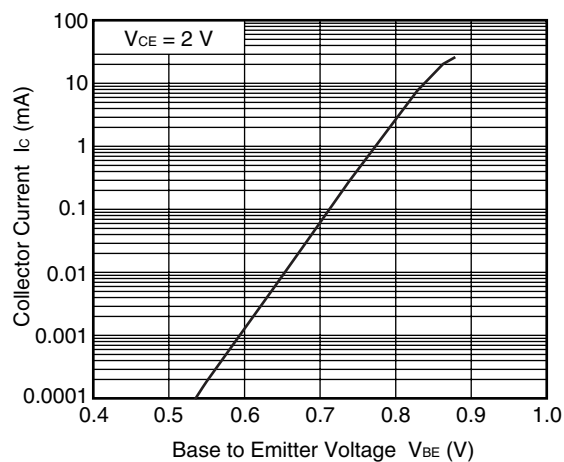
REVERSE TRANSFER CAPACITANCE  
vs. COLLECTOR TO BASE VOLTAGE



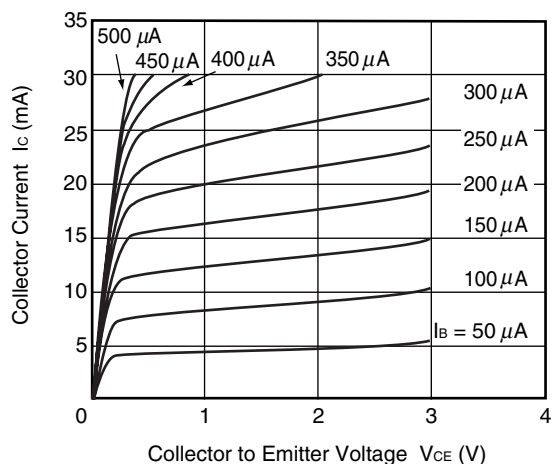
COLLECTOR CURRENT vs.  
BASE TO EMITTER VOLTAGE



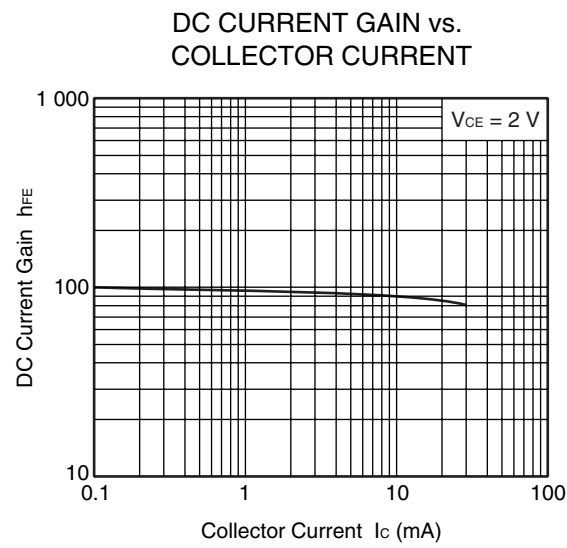
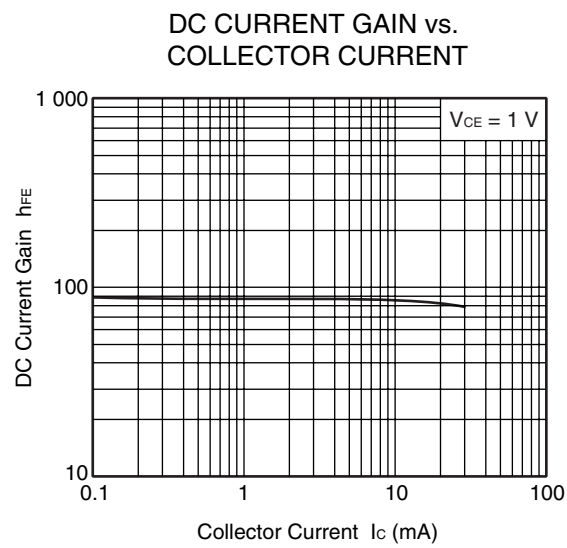
COLLECTOR CURRENT vs.  
BASE TO EMITTER VOLTAGE



COLLECTOR CURRENT vs.  
COLLECTOR TO EMITTER VOLTAGE



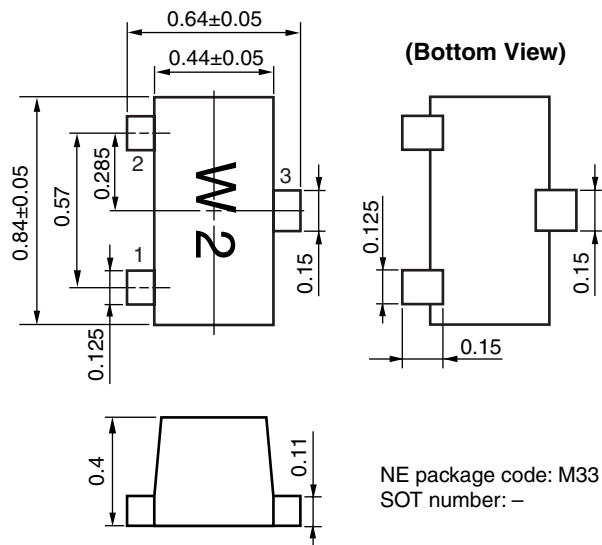
**Remark** The graphs indicate nominal characteristics.



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# PACKAGE DIMENSIONS

## 3-PIN SUPER LEAD-LESS MINIMOLD (M33) (UNIT: mm)



## PIN CONNECTIONS

1. Emitter
2. Base
3. Collector

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